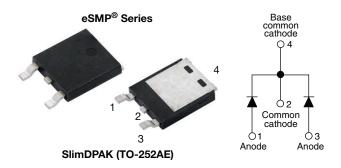
Vishay Semiconductors

www.vishay.com

Hyperfast Rectifier, 2 x 4 A FRED $Pt^{\mathbb{R}}$



LINKS TO ADDITIONAL RESOURCES



SHAY

| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|---------------------|--|--|--|--|
| I _{F(AV)} | 2 x 4 A | | | | |
| V _R | 200 V | | | | |
| V _F at I _F | 0.71 V | | | | |
| t _{rr} (typ.) | 16 ns | | | | |
| T _J max. | 175 °C | | | | |
| Package | SlimDPAK (TO-252AE) | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- Hyperfast recovery time
- 175 °C max. operating junction temperature
- Low forward voltage drop reduced Q_{rr} and soft recovery
- Low leakage current
- Very low profile typical height of 1.3 mm
 Polyimide passivation for high reliability standard
- Ideal for automated placement
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|------------|-----------------------------------|--------------------------------------|-------------|-------|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Peak repetitive reverse voltage | | V _{RRM} | | 200 | V | | |
| Average rectified forward current per leg per device | per leg | I _{F(AV)} | T _C = 167 °C | 4 | | | |
| | per device | | | 8 | А | | |
| Non-repetitive peak surge current per leg | | I _{FSM} | T_J = 25 °C, 10 ms sine pulse wave | 100 | | | |
| Operating junction and storage temperatures | | T _J , T _{Stg} | | -55 to +175 | °C | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|--------------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V_{BR} , V_{R} | I _R = 100 μA | 200 | - | - | | |
| | | I _F = 4 A | - | 0.88 | 1.0 | | |
| Forward voltage per leg | V _F | I _F = 8 A | - | 0.97 | 1.14 | V | |
| | | I _F = 4 A, T _J = 150 °C | - | 0.71 | 0.80 | | |
| | | I _F = 8 A, T _J = 150 °C | - | 0.8 | 1.0 | | |
| | | $V_R = V_R$ rated | - | - | 4 | | |
| Reverse leakage current per leg | I _R | $T_J = 125 \ ^{\circ}C, V_R = V_R \text{ rated}$ | - | - | 40 | μA | |
| | | $T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$ | - | - | 80 | | |
| Junction capacitance per leg | CT | V _R = 200 V | - | 17 | - | pF | |

Revision: 11-Jan-2021

Document Number: 95667

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1





www.vishay.com

Vishay Semiconductors

| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|------------------|--|---|------|------|-------|-------------|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 1$ | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ | | | - | |
| Reverse recovery time | t _{rr} | I _F = 0.5 A, I _R = 1 A, I _{RR} = 0.25 A | | - | - | 25 | |
| Reverse recovery time | | T _J = 25 °C | | - | 20 | - | - ns - A |
| | | T _J = 125 °C | | - | 30 | - | |
| Deals receivers ourrent | I _{RRM} | T _J = 25 °C | $I_F = 4 A$ | - | 2.5 | - | |
| Peak recovery current | | T _J = 125 °C | dl _F /dt = 200 A/µs V _B = 160 V | - | 4 | - | |
| Reverse recovery charge | Q _{rr} | T _J = 25 °C | | - | 25 | - | nC |
| | | T _J = 125 °C | | - | 60 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-------------------------------------|--------------------------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C |
| Thermal resistance, junction to ambient per diode | R _{thJA} ⁽¹⁾⁽²⁾ | | - | 73 | 90 | °C/W |
| Thermal resistance, junction to mount, per diode | R _{thJM} ⁽³⁾ | | - | 2.1 | 2.5 | °C/W |
| Marking device | | Case style SlimDPAK (TO-252AE) | | 8CV | 'H02 | |

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction to ambient; $dP_D/dT_J < 1 R_{thJA}$
- (2) Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} - junction to ambient

⁽³⁾ Mounted on infinite heatsink

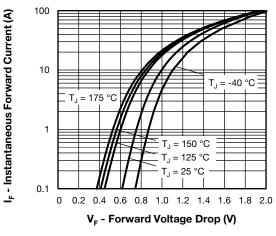


Fig. 1 - Typical Forward Voltage Drop Characteristics

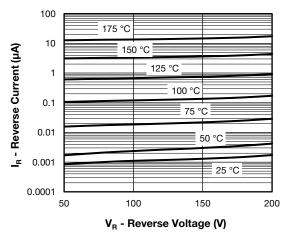


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Vishay Semiconductors

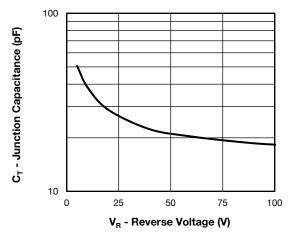


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

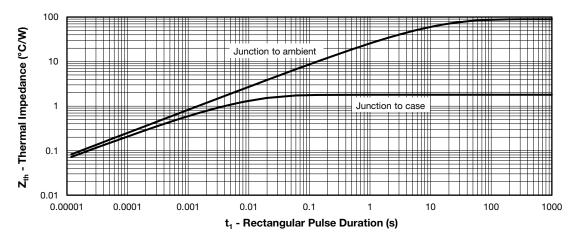
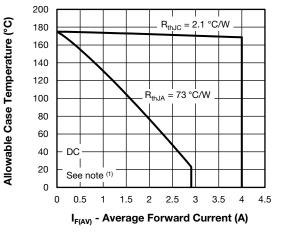
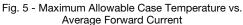


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)



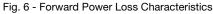


Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

5 4.5 RMS limit 4 3.5 3 2.5 D = 0.02 D = 0.05 2 D = 0.1 D = 0.2 1.5 D = 0.5 1 DC 0.5 0 3 4 0 2 5 6 I_{F(AV)} - Average Forward Current (A)



Document Number: 95667

Revision: 11-Jan-2021

SHAY

www.vishay.com

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

3



Vishay Semiconductors

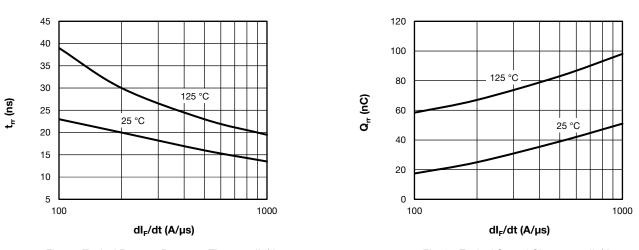


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

www.vishay.com

ISHAY



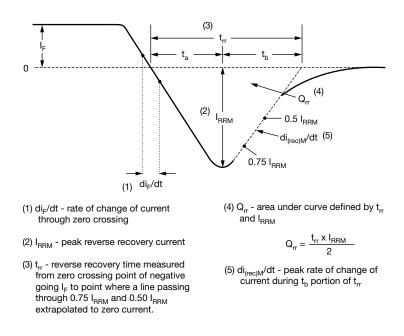


Fig. 9 - Reverse Recovery Waveform and Definitions

4

Vishay Semiconductors

www.vishay.com

ORDERING INFORMATION TABLE

VISHAY

| Device code | VS- | 8 | с | v | н | 02 | Н | М3 |
|-------------|-----|--------|---------------------|----------------|-----------|---------|---------|---------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |
| | 1 | - Visl | nay Sen | niconduo | ctors pro | oduct | | |
| | 2 · | - Cur | rent rati | ng (8 = | 8 A) | | | |
| | 3 - | - Circ | cuit conf | iguratio | า: | | | |
| | | C = | commo | n catho | de | | | |
| | 4 | • V = | SlimDP | AK | | | | |
| | 5 | | cess typ hyperfa | e, st recov | ery | | | |
| | 6 - | Vol | tage coo | de (02 = | 200 V) | | | |
| | 7 . | . н= | AEC-Q | 101 qua | lified | | | |
| | 8 - | - M3 | = halog | en-free, | RoHS- | complia | nt, and | termina |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|---|------|-----------------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTIO | | | | | |
| VS-8CVH02HM3/I | 4500 | 4500 | 13"diameter plastic tape and reel | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?96081 | | | | |
| Part marking information | www.vishay.com/doc?96085 | | | | |
| Packaging information | www.vishay.com/doc?88869 | | | | |

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

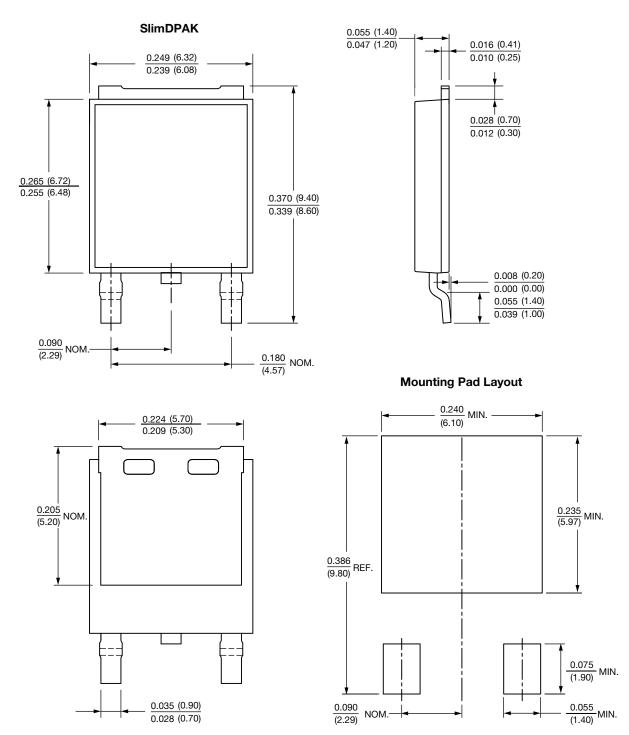


Outline Dimensions

Vishay Semiconductors

SlimDPAK

DIMENSIONS in inches (millimeters)





www.vishay.com

Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2021 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 VS-80-7161
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 CRS04(T5L,TEMQ)
 ACGRA4007-HF

 ACGRB207-HF
 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6002
 NTE6002
 NTE6039
 NTE6077

 85HFR60
 40HFR60
 1N1186RA
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K

 VS-12FL100S10
 ACGRA4001-HF
 D1821SH45T PR
 D1251S45T
 NTE5990
 NTE6358